## MN4094B/MN4094BS

### 8-Stage Shift-and-Store Bus Register

#### Outline

The MN4094B/S is a shift-and-store bus register consisting of an 8-bit shift register and an 8-bit latch.

It is possible to hold the output in the data transfer mode since each data read in the shift register can be read into the latch by the asynchronous strobe input. The parallel outputs can be directly connected to an 8-bit bus line since they are of 3-state structure. This shift-and-store bus register is suitable for application to a data serial/parallel converter, a data receiver, etc.

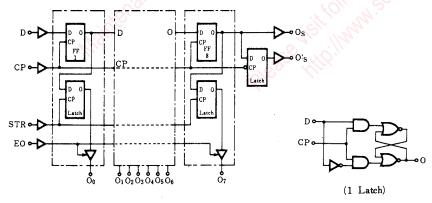
#### ■ Truth Table

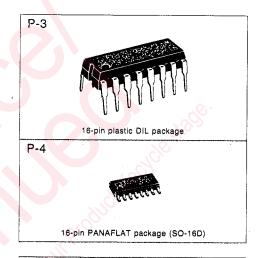
,	In	put		Parallel	Output	Serial Output		
CP	EO	STR	D	O <sub>o</sub>	On	$O_s$	O's	
	L	×	×	Z	Z	06	nc	
~	L	×	×	Z	Z	nc	O <sub>7</sub>	
	Н	L	×	nc	nc	06	nc	
	Н	Н	L	L	$O_{n-1}$	06	nc	
	Н	Н	Н	Н	$O_{n-1}$	O <sub>6</sub>	nc	
7	Н	Н	Н	nc	nc	nc	00	

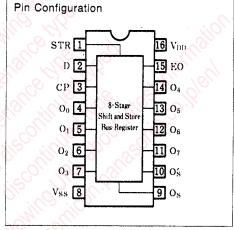
Note) × : don't care
Z : High impedance
nc : No change

O'6: State of shift resistor at 7th stage

#### ■ Logic Diagram









■ Absolute Maximum Ratings (Ta=25°C)

It	em	Symbol	Rating	Unit
Supply voltage		$V_{\scriptscriptstyle  m DD}$	-0.5~+18	V
Input voltage		V <sub>I</sub>	-0.5~V <sub>DD</sub> +0.5*	V
Output pin voltage		Vo	$-0.5 \sim V_{DD} + 0.5*$	V
Peak input · output pin current		$\pm I_{I}$	max. 10	. mA
Power dissipation	Ta=-40~+60°C	D	max. 400	.117
(per package)	Ta=+60~+80°C	$P_D$	Decrease to 200mW at the rate of 8mW/°C	mW
Power dissipation (per output pin)		PD	max. 100	mW
Operating ambient temperature		$T_{opr}$	-40~+85	°C
Storage temperature		$T_{\rm stg}$	$-65 \sim +150$	°C

<sup>\*</sup> V<sub>DD</sub>+0.5V should be lower than 18V.

#### ■ DC Characteristics (V<sub>SS</sub>=0V)

Item	$V_{DD}$	Symbol	Condition		Ta=-	-40°C	Ta=	a=25°C Ta=85°C			Unit
		V) Symbol Condition		min.	max.	min.	max.	min.	max.	UIII	
Static supply current					_	20	.00	20		150	
		$I_{\mathrm{DD}}$	$V_1 = V_{SS}$ or	$V_{\mathrm{DD}}$		40	17	40	—	300	μĄ
	15				_	80	_	80	-	600	
	5		V-V or	V		0.05	_	0.05	_	0.05	
Output voltage low level	10	Vol	$V_I = V_{SS}$ or $V_{DD}$		9	0.05		0.05	_	0.05	V
	15		$ I_0  < 1\mu A$		( <del>-</del>	0.05	_	0.05	_	0.05	
	5		V-V an	V	4.95		4.95	_	4.95	_	
Output voltage high level	10	V <sub>OH</sub>	$V_I = V_{SS}$ or $V_{DD}$		9.95	<b>–</b>	9.95		9.95	-<	V
	15		$ I_0  < 1\mu A$		14.95	_	14.95	_	14.95		
	5			V <sub>0</sub> =0.5V or 4.5V	_0	1.5	9	1.5	-,6	1.5	
Input voltage low level	10	$V_{IL}$	$ I_0  < 1\mu A$	$V_0=1V$ or $9V$		3	9_	3	( <del>Q</del> )	3	V
	15			$V_0 = 1.5 V$ or $13.5 V$	-2	4		4		4	
	5		7/	$V_0 = 0.5V$ or 4.5V	3.5	<u> </u>	3.5	5	3.5	<u> </u>	-
Input voltage high level	10	$V_{1H}$	$ I_0  < 1\mu A$	$V_0=1V$ or $9V$	7	<i> \</i>	7		7	_	V
	15			$V_0 = 1.5 \text{V or } 13.5 \text{V}$	11	9	11	<u> </u>	11		
	5		$V_0 = 0.4V$ ,	$V_i=0$ or $5V$	0.52		0.44	· (4)	0.36	_	
Output current low level	10	IOL	$V_0 = 0.5V$ , $V_1 = 0$ or $10V$		1.3	- 2)	1.1	2_	0.9		mA
	15	-0	$V_0 = 1.5V$ , $V_1 = 0$ or $15V$		3.6	<b>\</b>	3	_	2.4		
	5		$V_0 = 4.6V, V_1 = 0 \text{ or } 5V$		0.52	$\overline{}$	0.44		0.36		
Output current high level	10	$-I_{OH}$	$V_0 = 9.5V$ ,	$V_0 = 9.5V, V_1 = 0 \text{ or } 10V$		<u>, Q</u>	1.1		0.9		mA
	15		$V_0 = 13.5V$ , $V_1 = 0$ or 15V		3.6	_	3		2.4		
Output current high level	5	$-I_{OH}$	$V_0=2.5V, V_1=0 \text{ or } 5V$		1.7		1.4		1.1	_	mA
Input leakage current	15	±Ιι	V <sub>I</sub> =0 or 15			0.3	_	0.3		1	μΑ
3-state Leakage current high level	15	I <sub>ozh</sub>	$V_0 = V_{DD}$		_	1.6	_	1.6		12	
output pin Leakage current low level 15 $-I_{OZL}$ $V_O = V_{SS}$		68 31/13	_	1.6		1.6		12	$\mu$ A		

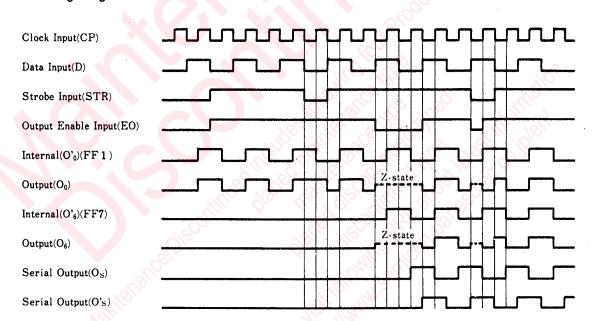
■ Switching Characteristics (Ta	a=25°C. V	/ <sub>ss</sub> =0V. (	מ05= <sub>ו</sub> C	F)
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<ul><li>Switching Characteristics</li></ul>		, V <sub>SS</sub> =0V,	C <sub>L</sub> =50pF)			
Item	V <sub>DD</sub> (V)	Symbol	min.	typ.	max.	Unit
	5			60	180	
Output rise time	10	$t_{TLH}$	_	30	90	ns
	15			20	60	
	5		_	60	180	
Output fall time	10	$t_{\mathtt{THL}}$		30	90	ns
	15			20	60	
Propagation time	5			135	405	
rropagation time CP→Os (H→L)	10	t <sub>PHL</sub>	_	65	195	ns
Cr→Os (n→L)	15			50	150	
D	5	$X \cap X \cap X$		105	315	Ø.
Propagation time	10	. t <sub>PLH</sub>	-	50	150	ns
CP→Os (H→H)	15			40	120	
D	5			105	315	
Propagation time	10	t <sub>PHL</sub>	_	50	150	ns
MR→O's (H→L)	15			40	120	
	5			105	315	
Propagation time	10	$t_{PLH}$	_	50	150	ns
MR→O's (L→H)	15		_	40	120	
	5		<	165	495	
Propagation time	10	t <sub>PHL</sub>	-(0)	75	225	ns
$CP \rightarrow On (H \rightarrow L)$	15		#	55	165	_
	5		1100	150	450	110
Propagation time	10	t <sub>PLH</sub>	011-0	70	210	ns
$CP \rightarrow On (L \rightarrow H)$	15	×C		55	165	
	5	. 65	70 200	110	330	100
Propagation time	10	$t_{\mathtt{PHL}}$	() _C	50	150	ns
STR→On (H→L)	15			35	105	.//
	5		×0'- ~	100	300	
Propagation time	10	t <sub>PLH</sub>	(), TO,	45	135	ns
STR→On (L→H)	15	O PELIN		35	105	
	5	3. /.	9, - 4	75	225	
High level output disab <mark>le</mark> time	10	t <sub>PHZ</sub>		40	120	ns
EO→On (H)	15	CPHZ	95 4	30	90	113
	5		- 1/1/2	80	240	
Low level output disable time	10	t	11011	40	120	ne
EO→On (L)	15	$t_{PLZ}$	101	30	90	ns
	5	·		40	120	
High level output enable time	10	, 4	1/1/19	25		<b></b>
EO→On (H)		t <sub>PZH</sub>	·0;/_		75	ns
	15			20	60	
Low level output enable time	5	<i>Sig.</i> ,		40	120	
EO→On (L)	10	t <sub>PZL</sub>	-	25	75	ns
	15			20	60	
Set-up time	5		_	30	90	
D→CP	10	$t_{su}$		10	30	ns
	15		_	5	15	

■ Switching Characteristics (cont.)

Item	$V_{DD}(V)$	Symbol	min.	typ.	max.	Unit
Hold time	5		5	-15	_	
D→CP	10	$t_{hold}$	. 20	5		ns
D⇒Cl	15		20	5		
	5		60	20	<u> </u>	
Minimum clock pulse width	10	twcpl	30	15	_	ns
	15		24	12	_	
	5		40	20	_	
Minimum strobe pulse width	10	twstrh	30	15		ns
·	15		24	12	<u> </u>	
	5		5	10		0,1
Maximum clock frequency	10	f <sub>max</sub>	11	22		MHz
•	15		14	28	-50	
Input capacitance		Cı			7.5	рF

## ■ Timing diagram



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